

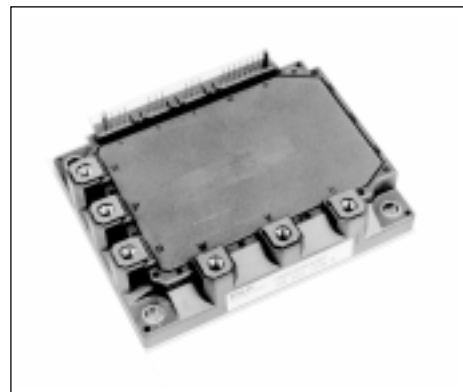
6MBP50RA120

IGBT-IPM R series

1200V / 50A 6 in one-package

Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- Compatible with existing IPM-N series packages
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



Maximum ratings and characteristics

- Absolute maximum ratings (at $T_c=25^\circ\text{C}$ unless otherwise specified)

| Item | Symbol | Rating | | Unit | | |
|--|-----------------------------|----------------|-------------|------------------|-----|---|
| | | Min. | Max. | | | |
| DC bus voltage | V_{bc} | 0 | 900 | V | | |
| DC bus voltage (surge) | $V_{bc}(\text{surge})$ | 0 | 1000 | V | | |
| DC bus voltage (short operating) | V_{sc} | 200 | 800 | V | | |
| Collector-Emitter voltage | V_{CES} | 0 | 1200 | V | | |
| INV | Collector current | DC | I_c | - | 50 | A |
| | | 1ms | I_{CP} | - | 100 | A |
| | | DC | $-I_c$ | - | 50 | A |
| | Collector power dissipation | One transistor | P_C | - | 357 | W |
| Junction temperature | T_j | - | 150 | $^\circ\text{C}$ | | |
| Input voltage of power supply for Pre-Driver | V_{CC}^{*1} | 0 | 20 | V | | |
| Input signal voltage | V_{in}^{*2} | 0 | V_z | V | | |
| Input signal current | I_{in} | - | 1 | mA | | |
| Alarm signal voltage | V_{ALM}^{*3} | 0 | V_{CC} | V | | |
| Alarm signal current | I_{ALM}^{*4} | - | 15 | mA | | |
| Storage temperature | T_{stg} | -40 | 125 | $^\circ\text{C}$ | | |
| Operating case temperature | T_{op} | -20 | 100 | $^\circ\text{C}$ | | |
| Isolating voltage (Case-Terminal) | V_{iso}^{*5} | - | AC2.5 | kV | | |
| Screw torque | Mounting (M5) | - | 3.5 *6 | N·m | | |
| | Terminal (M5) | - | 3.5 *6 | N·m | | |

*1 Apply V_{CC} between terminal No. 3 and 1, 6 and 4, 9 and 7, 11 and 10.

*2 Apply V_{in} between terminal No. 2 and 1, 5 and 4, 8 and 7, 13,14,15 and 10.

*3 Apply V_{ALM} between terminal No. 16 and 10.

*4 Apply I_{ALM} to terminal No. 16.

*5 50Hz/60Hz sine wave 1 minute.

*6 Recommendable Value : 2.5 to 3.0 N·m

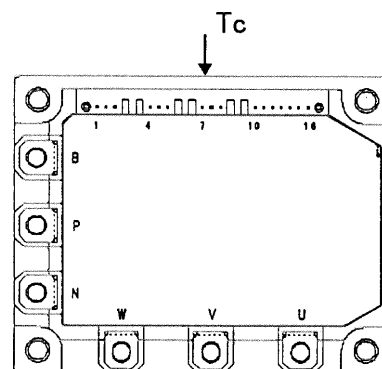


Fig.1 Measurement of case temperature

- Electrical characteristics of power circuit (at $T_c=T_j=25^\circ\text{C}$, $V_{CC}=15\text{V}$)

| Item | Symbol | Condition | Min. | Typ. | Max. | Unit | |
|------|---------------------------------------|----------------------|---|------|------|------|----|
| INV | Collector current at off signal input | I_{CES} | $V_{CE}=1200\text{V}$ input terminal open | - | - | 1.0 | mA |
| | Collector-Emitter saturation voltage | $V_{CE(\text{sat})}$ | $I_c=50\text{A}$ | - | - | 2.6 | V |
| | Forward voltage of FWD | V_F | $-I_c=50\text{A}$ | - | - | 3.0 | V |

● Electrical characteristics of control circuit(at $T_c=T_j=25^\circ\text{C}$, $V_{cc}=15\text{V}$)

| Item | Symbol | Condition | Min. | Typ. | Max. | Unit |
|--|--------------|---|------|------|------|------------------|
| Power supply current of P-line side Pre-driver(one unit) | I_{ccp} | fsw=0 to 15kHz $T_c=-20$ to 100°C *7 | 3 | - | 18 | mA |
| Power supply current of N-line side three Pre-driver | I_{ccn} | fsw=0 to 15kHz $T_c=-20$ to 100°C *7 | 10 | - | 65 | mA |
| Input signal threshold voltage (on/off) | $V_{in(th)}$ | ON | 1.00 | 1.35 | 1.70 | V |
| | | OFF | 1.25 | 1.60 | 1.95 | V |
| Input zener voltage | V_z | $R_{in}=20\text{k ohm}$ | - | 8.0 | - | V |
| Over heating protection temperature level | T_{COH} | $V_{DC}=0\text{V}$, $I_c=0\text{A}$, Case temperature | 110 | - | 125 | $^\circ\text{C}$ |
| Hysteresis | T_{CH} | | - | 20 | - | $^\circ\text{C}$ |
| IGBT chips over heating protection temperature level | T_{JOH} | surface of IGBT chips | 150 | - | - | $^\circ\text{C}$ |
| Hysteresis | T_{JH} | | - | 20 | - | $^\circ\text{C}$ |
| Collector current protection level | INV I_{OC} | $T_j=125^\circ\text{C}$ | 75 | - | - | A |
| Over current protection delay time | t_{DOC} | $T_j=25^\circ\text{C}$ Fig.2 | - | 10 | - | μs |
| Under voltage protection level | V_{UV} | | 11.0 | - | 12.5 | V |
| Hysteresis | V_H | | 0.2 | - | - | V |
| Alarm signal hold time | t_{ALM} | | 1.5 | 2 | - | ms |
| SC protection delay time | t_{SC} | $T_j=25^\circ\text{C}$ Fig.3 | - | - | 12 | μs |
| Limiting resistor for alarm | R_{ALM} | | 1425 | 1500 | 1575 | ohm |

*7 Switching frequency of IPM

● Dynamic characteristics(at $T_c=T_j=125^\circ\text{C}$, $V_{cc}=15\text{V}$)

| Item | Symbol | Condition | Min. | Typ. | Max. | Unit |
|-----------------------|-----------|---|------|------|------|---------------|
| Switching time (IGBT) | t_{on} | $I_C=50\text{A}$, $V_{DC}=600\text{V}$ | 0.3 | - | - | μs |
| | t_{off} | | - | - | 3.6 | μs |
| Switching time (FWD) | t_{rr} | $I_F=50\text{A}$, $V_{DC}=600\text{V}$ | - | - | 0.4 | μs |

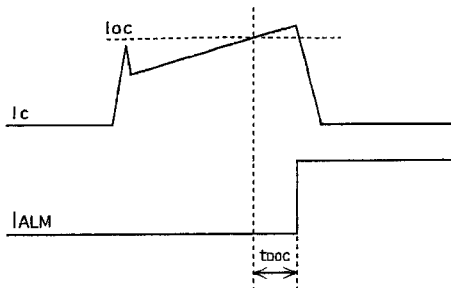


Fig.2 Definition of OC delay time

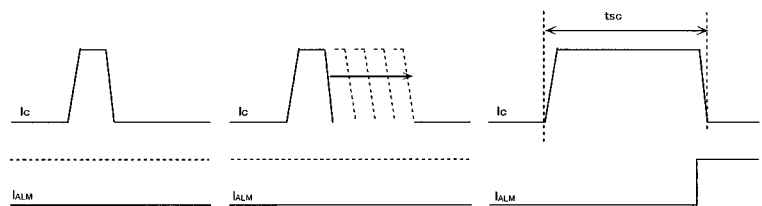


Fig.3 Definition of tsc

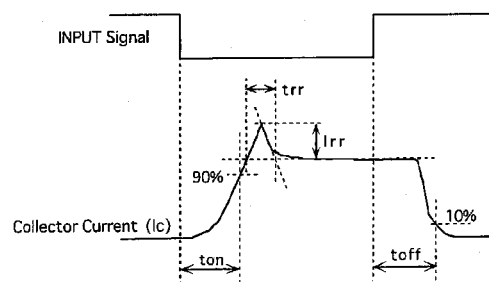


Fig.4 Definition of switching time

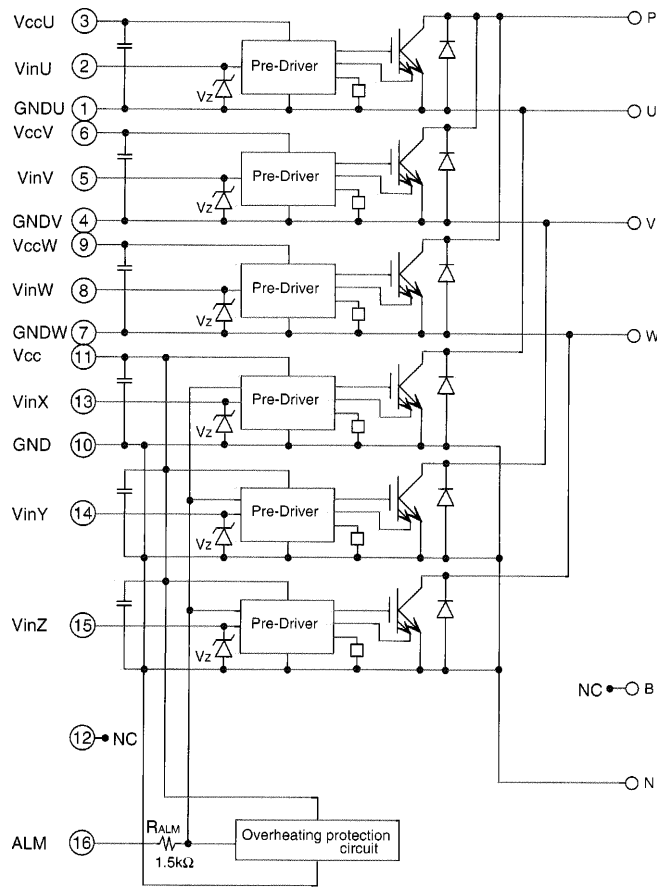
● Thermal characteristics($T_c=25^\circ\text{C}$)

| Item | Symbol | Typ. | Max. | Unit |
|--|---------------|------|------|--------------------|
| Junction to Case thermal resistance | INV IGBT | - | 0.35 | $^\circ\text{C/W}$ |
| | FWD | - | 0.85 | $^\circ\text{C/W}$ |
| Case to fin thermal resistance with compound | $R_{th(c-f)}$ | 0.05 | - | $^\circ\text{C/W}$ |

● Recommendable value

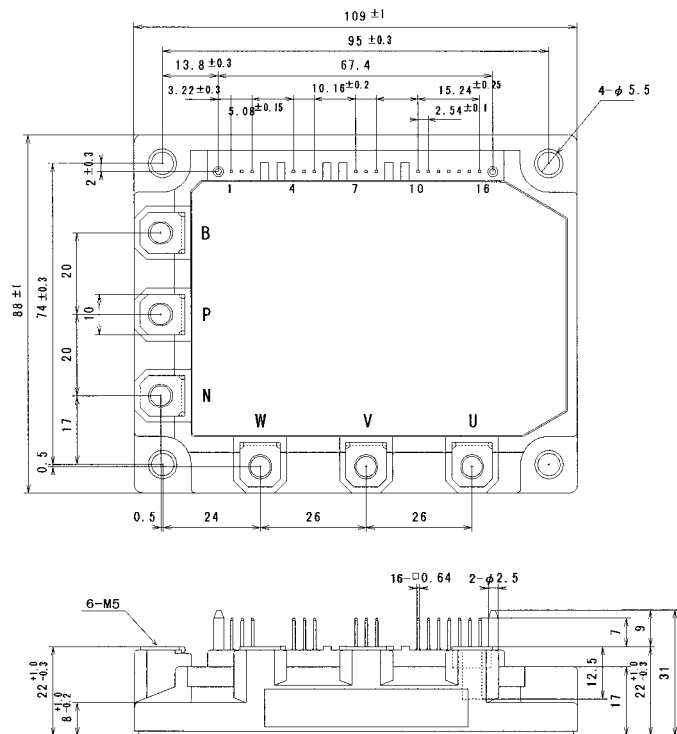
| Item | Symbol | Min. | Typ. | Max. | Unit |
|--|---------------|------|------|------|------|
| DC bus voltage | V_{DC} | 200 | - | 800 | V |
| Operating power supply voltage range of Pre-driver | V_{cc} | 13.5 | 15 | 16.5 | V |
| Switching frequency of IPM | fsw | 1 | - | 20 | kHz |
| Screw torque | Mounting (M5) | - | 2.5 | 3.0 | N·m |
| | Terminal (M5) | - | 2.5 | 3.0 | N·m |

Block diagram



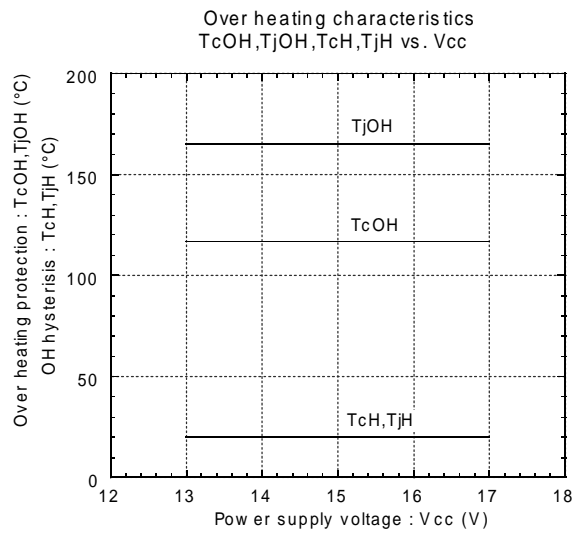
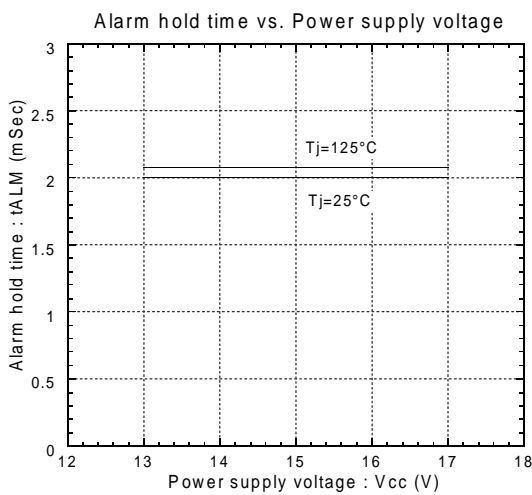
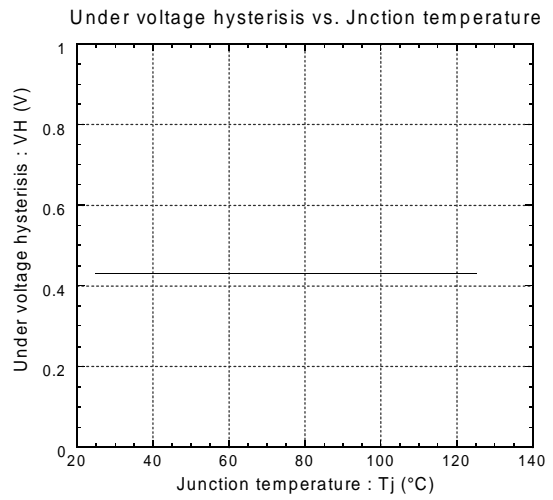
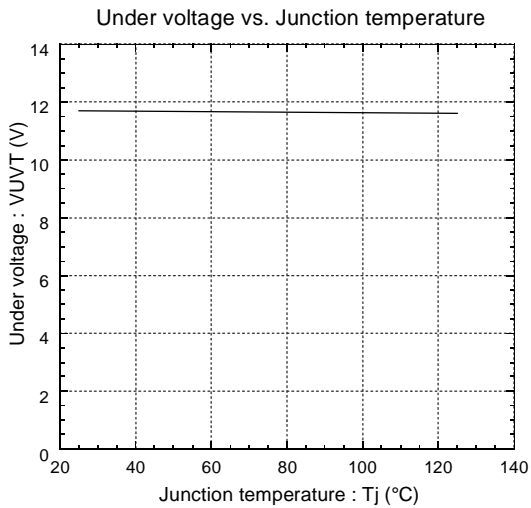
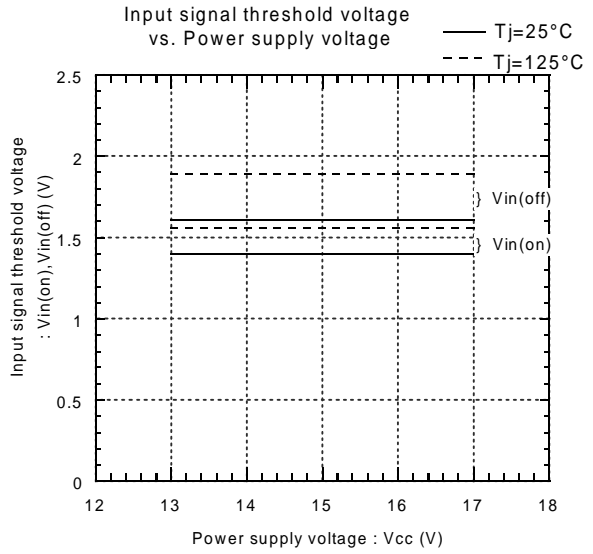
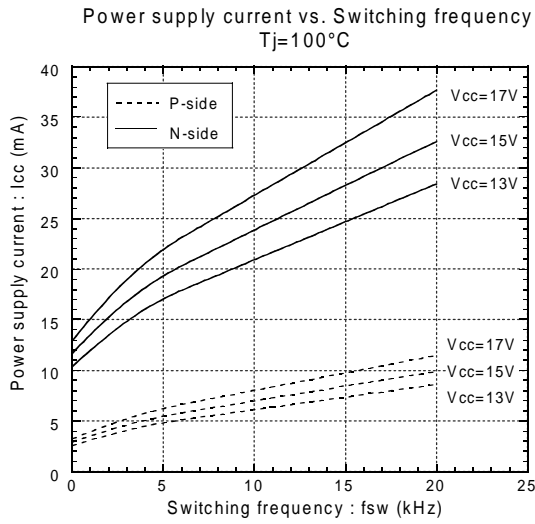
- Pre-drivers include following functions
- a) Amplifier for driver
 - b) Short circuit protection
 - c) Undervoltage lockout circuit
 - d) Over current protection
 - e) IGBT chip over heating protection

Outline drawings, mm



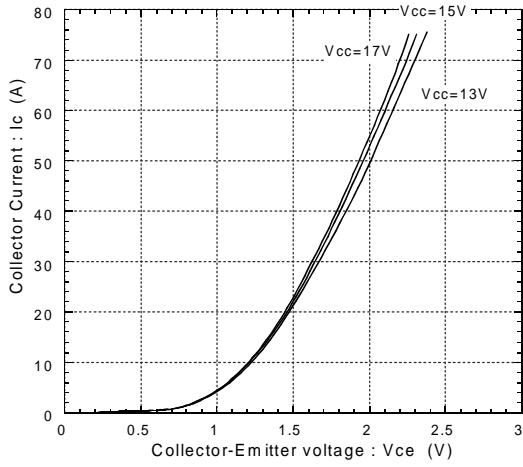
Characteristics (Representative)

Control Circuit

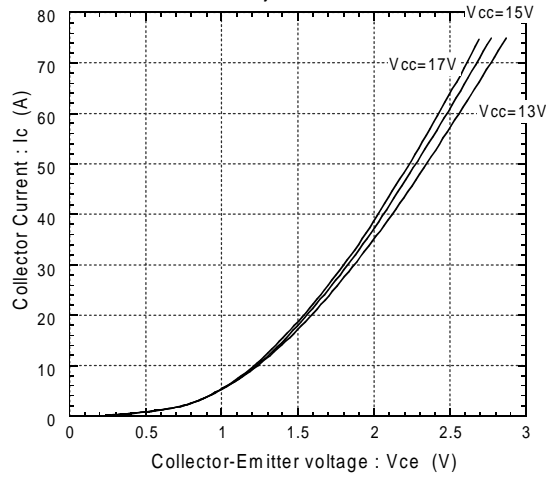


● Inverter

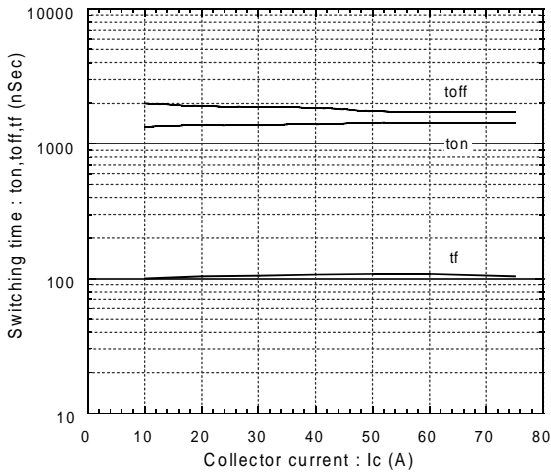
Collector current vs. Collector-Emittter voltage
T_j=25°C



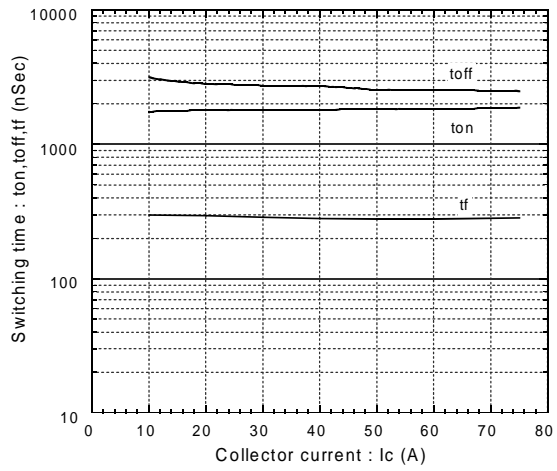
Collector current vs. Collector-Emittter voltage
T_j=125°C



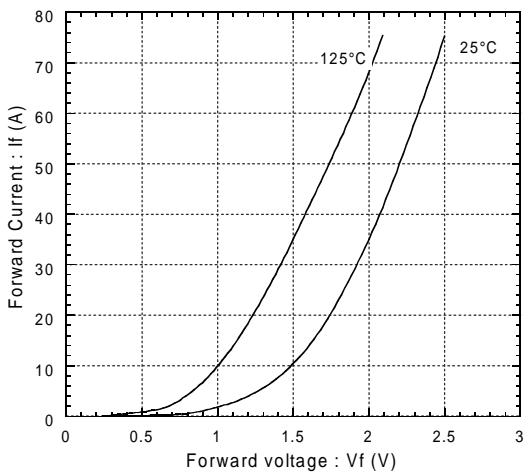
Switching time vs. Collector current
E_{dc}=600V, V_{cc}=15V, T_j=25°C



Switching time vs. Collector current
E_{dc}=600V, V_{cc}=15V, T_j=125°C



Forward current vs. Forward voltage



Reverse recovery characteristics
trr, Irr vs. IF

